

Continental Device India Limited

An ISO/TS16949 and ISO 9001 Certified Company



NPN SILICON PLANAR TRANSISTOR

B C E

2N917

TO-72 Metal Can Package

Amplifier Transistor

ABSOLUTE MAXIMUM RATINGS

| DESCRIPTION | SYMBOL | VALUE | UNIT |
|--|-----------------|-------------|-------|
| Collector Base Voltage | V_{CBO} | 30 | V |
| Collector Emitter Voltage | V_{CEO} | 15 | V |
| Emitter Base Voltage | V_{EBO} | 3 | V |
| Collector Current - Continuous | I _C | 50 | mA |
| Power Dissipation @ TA=25°C | P_{D} | 200 | mW |
| Derate Above 25°C | | 1.14 | mW/ºC |
| Power Dissipation @ T _C =25°C | P_{D} | 300 | mW |
| Derate Above 25°C | | 1.71 | mW/ºC |
| Operating & Storage Junction | T_{j},T_{stg} | -65 to +200 | ٥C |
| Temperature Range | | | |

ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

| DESCRIPTION | SYMBOL | TEST CONDITION | MIN | TYP | MAX | UNIT |
|---|-----------------------|---|-----|-----|-----|------|
| Collector Emitter Sustaining Voltage | V _{CEO(SUS)} | $_{\rm O}$ $I_{\rm C}$ =3mA, $I_{\rm B}$ =0 | 15 | - | - | V |
| Collector Base Voltage | V_{CBO} | $I_C=1\mu A,\ I_E=0$ | 30 | - | - | V |
| Emitter Base Voltage | V_{EBO} | $I_{E}=10\mu A, I_{C}=0$ | 3.0 | | - | V |
| Collector Cut off Current | I_{CBO} | $V_{CB}=15V$, $I_{E}=0$ | - | - | 1.0 | nA |
| | | VCB=15V, IE=0, TA=150°C | - | - | 1.0 | μΑ |
| DC Current Gain | h_{FE} | $I_C=3mA$, $V_{CE}=1V$ | 20 | - | 200 | |
| Collector Emitter Saturation Voltage | $V_{\text{CE(sat)}}$ | $I_C=10mA$, $I_B=1mA$ | - | - | 0.4 | V |
| Base Emitter Saturation Voltage | $V_{BE(sat)}$ | $I_C=10$ mA, $I_B=1$ mA | - | - | 1.0 | V |

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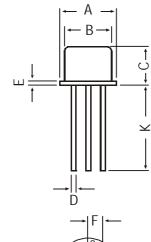
ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

| DESCRIPTION | SYMBOL TEST CONDITION | | MIN | TYP | MAX | UNIT |
|------------------------------------|-----------------------|--|-----|-----|-----|------|
| Small-Signal Characteristics | | | | | | |
| Current - Gain - Bandwidth Product | $f_T(1)$ | $I_C=4mA, V_{CE}=10V, f=100MHz$ | 600 | - | - | MHz |
| OutPut Capacitance | C_obo | V_{CB} =10V, I_E =0, f=140kHz | - | - | 2.0 | pF |
| | | V_{CB} =0V, I_E =0, f=140kHz | - | - | 3.0 | pF |
| InPut Capacitance | C_lbo | V_{EB} =0.5V, I_{C} =0, f=140kHz | - | - | 2.0 | pF |
| Noise Figure | NF | $I_C=1$ mA, $V_{CE}=6$ V, | - | - | 6.0 | dB |
| - | | R_G =400 Ω , f=60MHz | | | | |
| Functional Test | | | | | | |
| Amplifier Power Gain | G_pe | V_{CB} =12V, I_{C} =6mA, f =200MHz | 15 | - | - | dB |
| Power Output | Po | V_{CB} =15V, I_{C} =8mA, f=500MHz | 30 | - | - | mW |
| Collector Efficiency | π | V_{CB} =15V, I_{C} =8mA, f=500MHz | 25 | - | - | % |

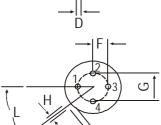
⁽¹⁾ fT is defined as the frequency at which $Ih_{fe}I$ extrapolates to unity.

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PIN CONFIGURATION

- 1. EMITTER
- 2. BASE
- 3. COLLECTOR
- 4. CASE

| | DIM | MIN. | MAX. |
|-------------------|-----|--------|--------|
| | Α | 5.24 | 5.84 |
| | В | 4.52 | 4.95 |
| | С | 4.31 | 5.33 |
| | D | 0.40 | 0.53 |
| | Е | | 0.76 |
| | F | 1.14 | 1.39 |
| almensions in mm. | G | 2.28 | 2.97 |
| ns in | Н | 0.91 | 1.17 |
| ISIOI | J | 0.71 | 1.22 |
| ılme | K | 12.70 | _ |
| All o | L | 12 DEG | 48 DEG |

Packing Detail

| PACKAGE | STANDARD PACK | | INNER CARTON BOX | | OUTER CARTON BOX | | |
|---------|---------------|----------------|------------------|-----|-------------------|-----|--------|
| | Details | Net Weight/Qty | Size | Qty | Size | Qty | Gr Wt |
| T0-72 | 1 K/Polybag | 325 gm/1K pcs | 3" x 7.5" x 7.5" | 5K | 17" x 15" x 13.5" | 80K | 32 kgs |

Notes 2N917

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Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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